

View Online at <https://aerobasegroup.com/nsn/5962-01-171-5126>

**Storage Temperature Range:**

-65.0/+150.0 degrees celsius

**Features Provided:**

Bipolar and programmable and hermetically sealed and high impedance and low level

**Inclosure Material:**

Ceramic

**Inclosure Configuration:**

Dual-in-line

**Output Logic Form:**

Transistor-transistor logic

**Input Circuit Pattern:**

6 input

**Case Outline Source And Designator:**

D-3 mil-m-38510

**Terminal Surface Treatment:**

Solder

**Voltage Rating And Type Per Characteristic:**

5.5 volts power source

**Memory Device Type:**

Rom

**Test Data Document:**

81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

**Terminal Type And Quantity:**

24 printed circuit

**Shelf Life:**

N/a

**Unit Of Measure:**

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**Demilitarization:**

Yes - demil/mli

**Fiig:**

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